

SPECIFICATION FOR APPROVAL

CUSTOMER : _____

PRODUCT TYPE : SMD TSX 2.0*1.6

NOMINAL FREQ. : 19.2 MHz

TXC P/N : OY19270002

REVISION : S1

CUSTOMER P/N : _____

PM / SALES : _____

DATE : 2012/5/30

CUSTOMER SIGNATURE & DATE
: _____

- (1) TXC requires one copy returned with signature and title of authorized individual that signifies acceptance of the attached specifications.
- (2) Orders received and accepted by TXC after return of signed copy of specification will be produced per these specifications.
- (3) Any changes to these specifications must be agreed upon by both parties and new revision of the Product Specification Sheet will be issued.
- (4) Any issuance of purchase order prior to consigning back the Approval page of "Specification Sheets" from customers will be regarded as the agreement on the contents of these specifications.

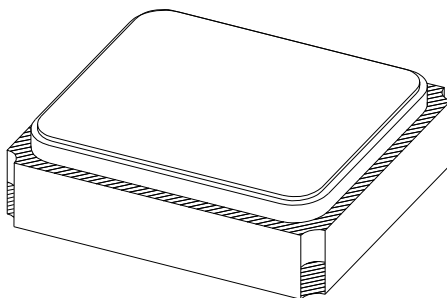
Attachment(s):

- 1. Product Specification Sheet
- 2. Testing Report(Electrical & Temperature)
- 3. Reliability Report

RoHS Compliant

PRODUCT SPECIFICATION SHEET

CUSTOMER : _____
PRODUCT TYPE : SMD TSX 2.0*1.6
NOMINAL FREQ. : 19.2 MHz
TXC P/N : OY19270002
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RD	QA	MFG
Bruce Hsu Kenneth Kao		
2012/5/30		

NOTE:

- (1) Lead Free Products are " Directive 2002 / 95 / EC of The European Parliament of 27 January 2003 on the restriction of the use of certain hazardous substances (RoHS) in electrical and electronic equipment" Compliant (Attachment: SGS Test Report).
- (2) Revision "Sx" is for engineering samples only. PE/RD's approval required.
- (3) Revision "Ax" is production ready. PE, QA and MFG's approval required.

RoHS Compliant

PRODUCT TYPE : SMD TSX 2.0*1.6

P/N : OY19270002

REVISION : S1

■ CRYSTAL ELECTRICAL SPECIFICATIONS

Standard Atmospheric Conditions

Unless otherwise specified, the standard range of atmospheric conditions for making measurement and tests are as follow:

Ambient temperature : 25±10°C
 Relative humidity : 40%~70%

If there is any doubt about the results, measurement shall be made within the following limits:

Ambient temperature : 25±3°C
 Relative humidity : 40%~70%

Measurement Equipment

Electrical characteristics measured by HP E5100A or equivalent

Crystal Cutting Type

The crystal is using AT CUT (thickness shear mode)

	Parameters	Symbol	Condition	Electrical Spec.				Note
				Min.	Typ.	Max.	Units	
1	Nominal Frequency	FL		19.200000			MHz	
2	Oscillation Mode	-		Fundamental				
3	Load Capacitance	CL			7		pF	1
4	Frequency Tolerance	-	+25°C ± 3°C			±10	ppm	
5	Tolerance Over Temperature	-	-30°C to +85°			±12	ppm	2
6	Frequency Drift After Reflow	-	two reflows			±2	ppm	
7	Operating Temperature	-		-30		+105	°C	
8	Aging	-				±0.7	ppm/Year	
9	Drive Level	DL		10		100	µW	
10	Effective Resistance R _r	R _r				80	Ω	
11	Shunt Capacitance C ₀	C ₀		0.3		1.3	pF	
12	Motional Capacitance C ₁	C ₁		1.8		3.1	fF	
13	Insulation Resistance	-	at DC 100 V	500			MΩ	
14	Storage Temperature Range	-	-	-40		+105	°C	
15	Spurious Mode Series Resistance	-	±1 MHz	1100			Ω	
16	Q Factor	Q		75000				3
17	First-order Curve Fitting Parameter	-		-0.4		-0.1	ppm/°C	4
18	Second-order Curve Fitting Parameter	-		-4.5	0	4.5	x10 ⁻⁴ ppm/°C ²	4
19	Third-order Curve Fitting Parameter	-		8.5	10	11.5	x10 ⁻⁵ ppm/°C ³	4
20	Residual frequency stability slope	-				±50	ppb/°C	5
21	5°C small orbit hysteresis 1	-				±50	ppb/°C	6
22	5°C small orbit hysteresis 2	-			100		ppb pk-pk	7

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	Parameters	Symbol	Condition	Electrical Spec.				Note
				Min.	Typ.	Max.	Units	
23	DLD Freq (Max-Min)	-				3.0	ppm	8
24	DLD Freq (Repeatability)	-				0.7	ppm	8
25	DLD ESR (Max-Min)	-				20	%	8
26	DLD ESR (Repeatability)	-				10	%	8

Note 1 The load capacitance is measured according to IEC Standard #60444-7

Note 2 Above 85°C tolerance over temperature bound by third-order coefficient range

Note 3 Minimum Q value calculated from ESR and L is smaller than this specification

Note 4 The curve fitting parameter is obtained from the Qualcomm crystal curve fitting algorithm, $t_0=32\text{ }^\circ\text{C}$
(Refer to Curve Fitting Calculation Table: 80-V9690-26 Rev.C)

Note 5 Condition 1A – Test condition (continuous temperature rate change of $\sim 1.0\text{ }^\circ\text{C}/\text{min}$):

- Measure FT points every $1\text{ }^\circ\text{C}$, heating up from -30 to $+85\text{ }^\circ\text{C}$, subtract a fifth-order polynomial best fit and then calculate the slope of the residual.
- The residual slope should be within $\pm 50\text{ ppb}/^\circ\text{C}$.

Note 6 Condition 1B – Hysteresis 1 test condition (continuous temperature rate change of $\sim 1.0\text{ }^\circ\text{C}/\text{min}$):

- Measure FT points every $0.5\text{ }^\circ\text{C}$ while cycling temperature over a $5\text{ }^\circ\text{C}$ small temperature orbit; an example $5\text{ }^\circ\text{C}$ small orbit temperature cycle is $+30\text{ }^\circ\text{C}$ to $+35\text{ }^\circ\text{C}$ to $+30\text{ }^\circ\text{C}$.
- During every individual heating/cooling cycle there should be 11 points; discard the first point of each heating and cooling cycle; this leaves 10 points for each heating and cooling cycle. Subtract the fifth-order polynomial best fit from 1A for each of the 10 points, and then calculate the slope of the residual for each of these heating and cooling 10 point curves.
- The residual slope should be within $\pm 50\text{ ppb}/^\circ\text{C}$.

Note 7 Hysteresis 2 test condition (continuous temperature rate change of $\sim 1.0\text{ }^\circ\text{C}/\text{min}$):

- Measure FT points every $0.5\text{ }^\circ\text{C}$ while cycling temperature over a $5\text{ }^\circ\text{C}$ small temperature orbit; an example $5\text{ }^\circ\text{C}$ small orbit temperature cycle is $+30\text{ }^\circ\text{C}$ to $+35\text{ }^\circ\text{C}$ to $+30\text{ }^\circ\text{C}$.
- During every individual heating/cooling cycle there should be 11 points; discard the first and last point of each heating and cooling cycle, which results in 9 temperature points. Calculate the average measured peak-to-peak frequency difference for these 9 temperature points.
- The average difference is the magnitude of the small orbit hysteresis 2.

Note 8 $0.01\text{ }^\mu\text{W}$ to $100\text{ }^\mu\text{W}$ to $0.01\text{ }^\mu\text{W}$, number of points: 15 points up and 15 points down = 29 total data points

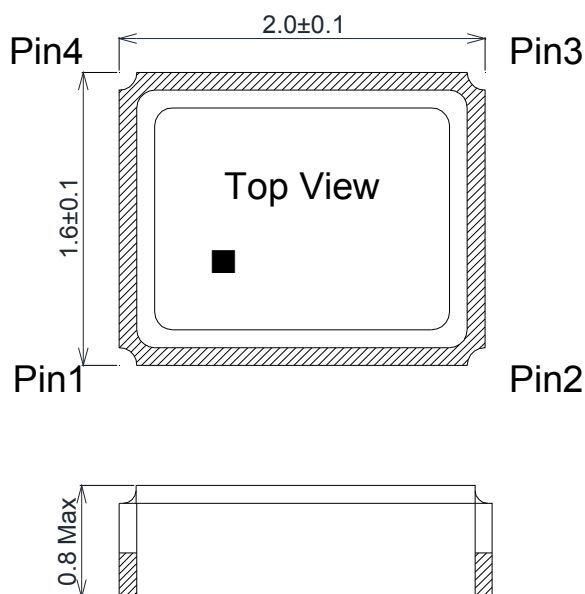
Note 9 This crystal specification complies to Qualcomm Mini-Specification 80-V9690-26 Rev.C

NTC THERMISTOR ELECTRICAL SPECIFICATIONS

	Parameters	Symbol	Condition	Electrical Spec.				Note
				Min.	Typ.	Max.	Units	
1	Resistance (25 °C)			100k ± 1%			Ω	
2	B-Constant (25-50 °C)			4250 ± 1%			K	1
3	Operating Temperature			-30		+105	°C	

Note 1 The B constant is calculated using the zero-power resistance values measured at 25°C and 50°C

DIMENSIONS

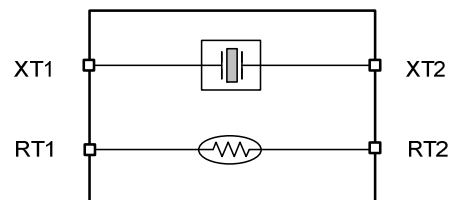


PIN FUNCTION

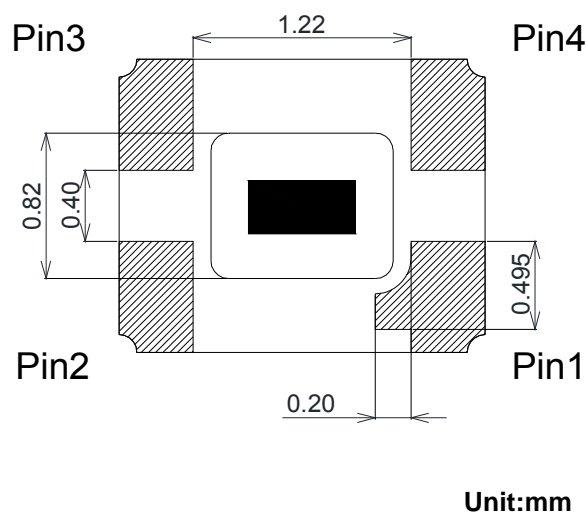
	Symbol	Function
Pin 1	XT1	XTAL Terminal 1
Pin 2	RT2	Thermistor Terminal 2
Pin 3	XT2	XTAL Terminal 2
Pin 4	RT1	Thermistor Terminal 1

Note: Pin 2 is connected to the metal lid and thermistor
Pin 4 is connected to the thermistor only

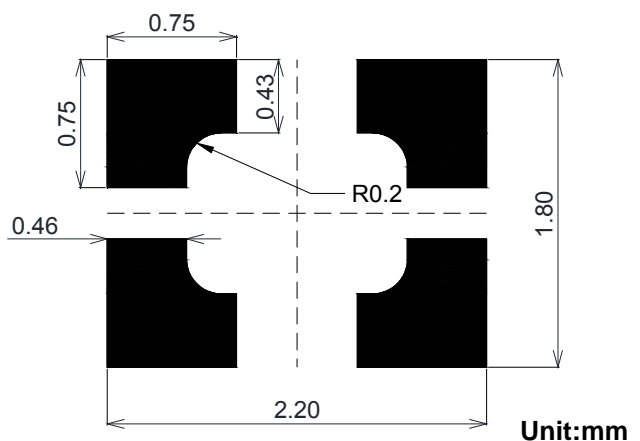
BLOCK DIAGRAM



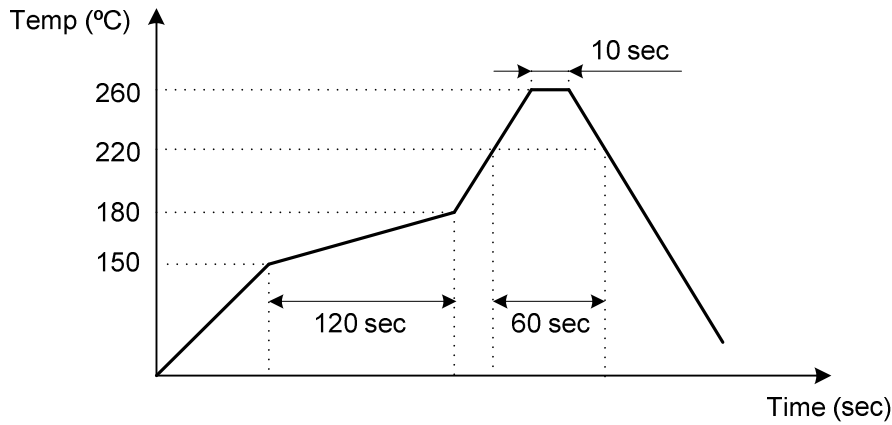
Note: RT2 shall be connected to GND is recommended



SUGGESTED LAYOUT

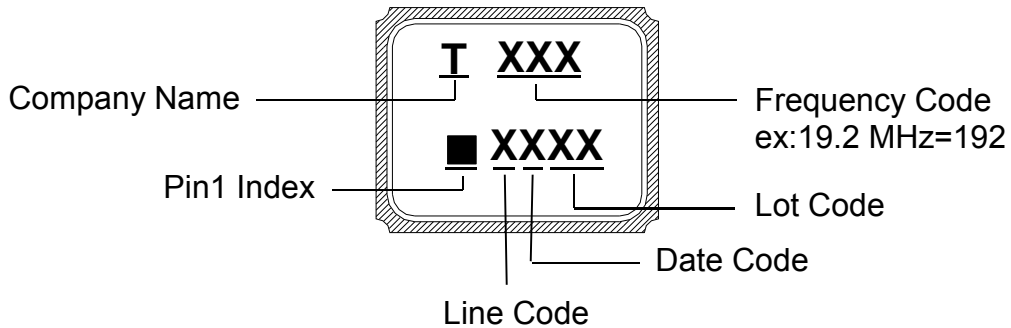


■ SUGGESTED REFLOW PROFILE



Note : Total Time: 200 sec. Max., Solder Melting Point: 220°C

■ MARKING

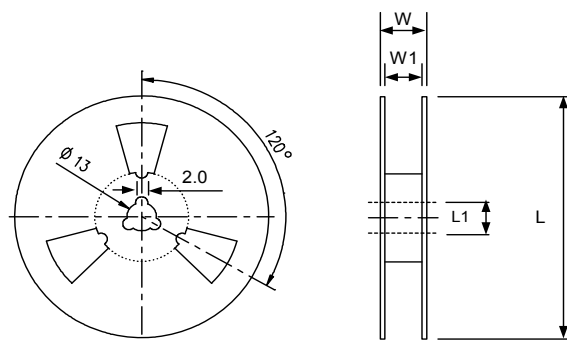
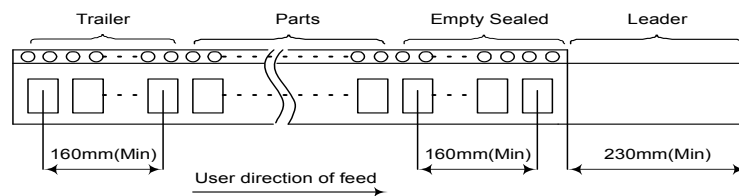
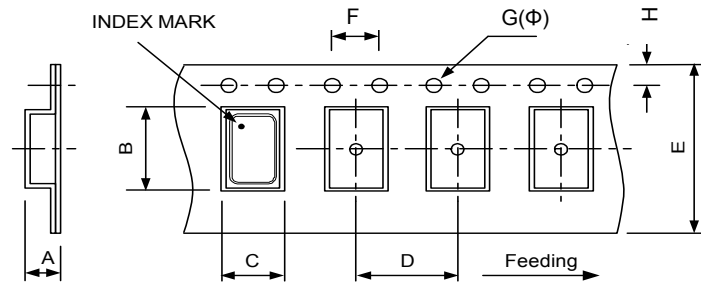


DATE CODE

MONTH				JAN	FEB	MAR	APR	MAY	JUN	JUL	AUG	SEP	OCT	NOV	DEC
YEAR															
2005	2009	2013	2017	A	B	C	D	E	F	G	H	J	K	L	M
2006	2010	2014	2018	N	P	Q	R	S	T	U	V	W	X	Y	Z
2007	2011	2015	2019	a	b	c	d	e	f	g	h	j	k	l	m
2008	2012	2016	2020	n	p	q	r	s	t	u	v	w	x	y	z

Note: This date code will be cycled every four years

■ PACKING : (EIA-481-2)



Unit: mm

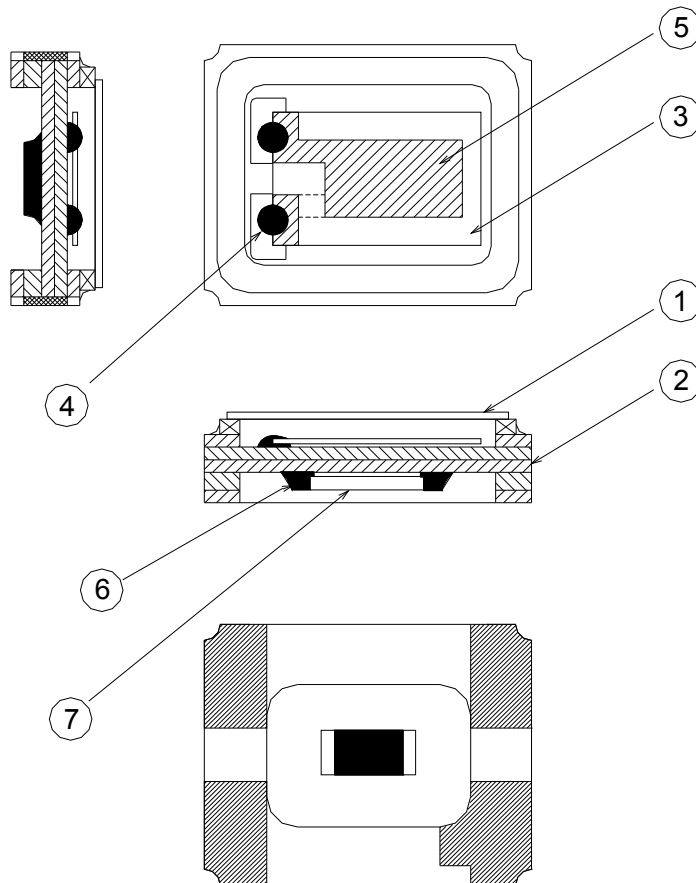
DIMENSIONS (mm)	A	B	C	D	E	F	G	H	L	L1	W	W1	Standard Reel Quantity is 3,000 pcs per reel
	0.65	2.30	1.90	4.00	8.00	4.00	1.55	1.75	178	13.0	11.5	8.0	

■ WEIGHT

0.0086 g / piece(TYP), 26 ± 1.3 g /3 kpcs(regardless of tape weight)

■ **STRUCTURE ILLUSTRATION**

Crystal Enclosure Seal : Seam Welding



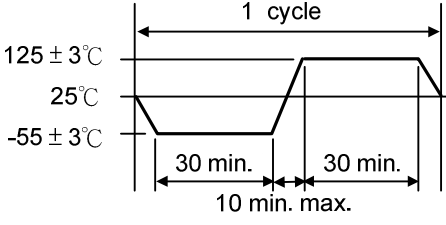
No.	COMPONENTS	MATERIALS	FINISH/SPECIFICATIONS
1	Lid	Metal (Fe+Co+Ni)	-
2	Base (Package)	Ceramic (Al ₂ O ₃) + Kovar (Fe+Co+Ni) + Ag/Cu	Alumina Ceramics
3	Crystal Blank	SiO ₂	-
4	Conductive Adhesive	Ag	Silicone Resin
5	Electrode	Noble Metal	-
6	Solder	Sn	-
7	Thermistor	Al ₂ O ₃ , Ag, Ni	-

RELIABILITY SPECIFICATIONS

1. Mechanical Endurance

No.	Test Item	Test Methods	Reference
1.1	Drop Test	150 cm height, 3 times on concrete floor.	JIS C6701
1.2	Mechanical Shock	Device are shocked to half sine wave (1000 G) three mutually perpendicular axes each 3 times. 0.5 msec. duration time	MIL-STD-202
1.3	Vibration	Frequency range 10 ~ 2000 Hz Amplitude 1.52 mm/20 G Sweep time 20 minutes Perpendicular axes each test time 4 Hrs (Total test time 12 Hrs)	MIL-STD-883
1.4	Gross Leak	Standard sample for automatic gross leak detector Test pressure: 2 kg / cm ²	MIL-STD-883
1.5	Fine Leak	Helium bombing 4.5 kg/ cm ² for 2 Hrs	
1.6	Solderability	Temperature 245°C ± 5°C Immersing depth 0.5 mm minimum Immersion time 5 ± 1 seconds Flux Rosin resin methyl alcohol solvent (1 : 4)	MIL-STD-883

2. Environmental Endurance

No.	Test Item	Test Methods	Reference
2.1	Resistance To Soldering Heat	Pre-heat temperature 125°C Pre-heat time 60 ~ 120 sec. Test temperature 260 ± 5°C Test time 10 ± 1 sec.	MIL-STD-202
2.2	High Temp. Storage	+ 125 °C ± 3 °C for 500 ± 12 Hrs	MIL-STD-883
2.3	Low Temp. Storage	- 40°C ± 3°C for 500 ± 12 Hrs	
2.4	Thermal Shock	Total 100 cycles of the following temperature cycle 	MIL-STD-883
2.5	High Temp & Humidity	85°C ± 3°C, RH 85% , 500 Hrs	JIS C5023